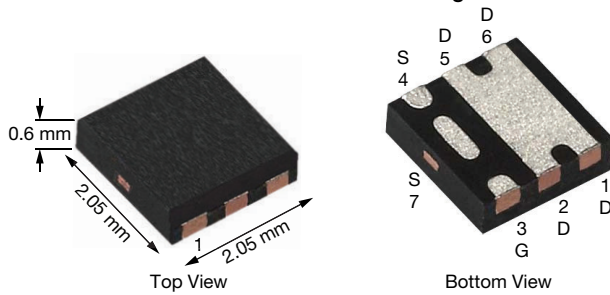




**THE DATASHEET OF
SIA477EDJT-T1-GE3**



P-Channel 12 V (D-S) MOSFET

Thin PowerPAK® SC-70-6L Single

Marking code: B7

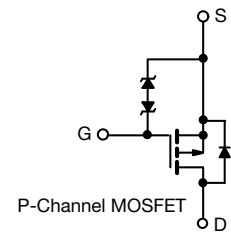
PRODUCT SUMMARY	
V_{DS} (V)	-12
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.0130
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -3.7$ V	0.0145
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -2.5$ V	0.0190
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -1.8$ V	0.0320
Q_g typ. (nC)	33
I_D (A)	-12
Configuration	Single

FEATURES

- TrenchFET® Gen III p-channel power MOSFET
- Thermally enhanced PowerPAK® SC-70 package
 - Small footprint area
 - Low on-resistance
- 100 % R_g tested
- $R_{DS(on)}$ rating at $V_{GS} = -1.8$ V
- Built in ESD protection with Zener diode
- Typical ESD performance: 3500 V
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE
APPLICATIONS

- Smart phones, tablet PCs, mobile computing
 - Battery switch
 - Charger switch
 - Load switch



ORDERING INFORMATION	
Package	Thin PowerPAK SC-70-6L
Lead (Pb)-free and halogen-free	SiA477EDJT-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage	V_{DS}	-12	V	
Gate-source voltage	V_{GS}	± 8		
Continuous drain current ($T_J = 150$ °C)	I_D	$T_C = 25$ °C	-12 ^a	A
		$T_C = 70$ °C	-12 ^a	
		$T_A = 25$ °C	-12 ^{a, b, c}	
		$T_A = 70$ °C	-11 ^{b, c}	
Pulsed drain current ($t = 100$ μ s)	I_{DM}	-50		
Continuous source-drain diode current	I_S	$T_C = 25$ °C	-12 ^a	
		$T_A = 25$ °C	-2.9 ^{b, c}	
Maximum power dissipation	P_D	$T_C = 25$ °C	19	W
		$T_C = 70$ °C	12	
		$T_A = 25$ °C	3.5 ^{b, c}	
		$T_A = 70$ °C	2.2 ^{b, c}	
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +150	°C	
Soldering recommendations (peak temperature) ^{d, e}		260		

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	TYPICAL	MAXIMUM	UNIT	
Maximum junction-to-ambient ^{b, f}	R_{thJA}	28	36	°C/W	
Maximum junction-to-case (drain)	R_{thJC}	5.3	6.5		

Notes

- Package limited
- Surface mounted on 1" x 1" FR4 board
- $t = 5$ s
- See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- Maximum under steady state conditions is 80 °C/W



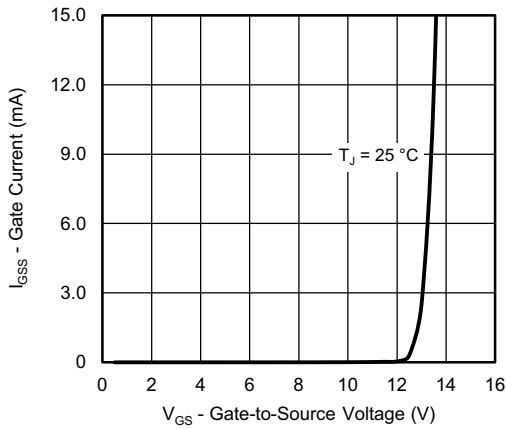
SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0\text{ V}$, $I_D = -250\text{ }\mu\text{A}$	-12	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	$I_D = -250\text{ }\mu\text{A}$	-	-3.9	-	mV/ $^\circ\text{C}$
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$		-	2.5	-	
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250\text{ }\mu\text{A}$	-0.4	-	-1	V
Gate-source leakage	I_{GSS}	$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 8\text{ V}$	-	-	± 12	μA
		$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 4.5\text{ V}$	-	-	± 1	
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -12\text{ V}$, $V_{GS} = 0\text{ V}$	-	-	-1	
		$V_{DS} = -12\text{ V}$, $V_{GS} = 0\text{ V}$, $T_J = 55\text{ }^\circ\text{C}$	-	-	-10	
On-state drain current ^a	$I_{D(on)}$	$V_{DS} \leq -5\text{ V}$, $V_{GS} = -4.5\text{ V}$	-20	-	-	A
Drain-source on-state resistance ^a	$R_{DS(on)}$	$V_{GS} = -4.5\text{ V}$, $I_D = -5\text{ A}$	-	0.0110	0.0130	Ω
		$V_{GS} = -3.7\text{ V}$, $I_D = -5\text{ A}$	-	0.0114	0.0145	
		$V_{GS} = -2.5\text{ V}$, $I_D = -3\text{ A}$	-	0.0145	0.0190	
		$V_{GS} = -1.8\text{ V}$, $I_D = -1\text{ A}$	-	0.0228	0.0320	
Forward transconductance ^a	g_{fs}	$V_{DS} = -6\text{ V}$, $I_D = -5\text{ A}$	-	30	-	S
Dynamic ^b						
Input capacitance	C_{iss}	$V_{DS} = -6\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	-	3050	-	pF
Output capacitance	C_{oss}		-	725	-	
Reverse transfer capacitance	C_{rss}		-	740	-	
Total gate charge	Q_g	$V_{DS} = -6\text{ V}$, $V_{GS} = -10\text{ V}$, $I_D = -10\text{ A}$	-	55	83	nC
		$V_{DS} = -6\text{ V}$, $V_{GS} = -4.5\text{ V}$, $I_D = -10\text{ A}$	-	33	50	
-	4.3		-			
-	8.9		-			
Gate-source charge	Q_{gs}	$f = 1\text{ MHz}$	1.2	6	12	Ω
Gate-drain charge	Q_{gd}		-	6	12	
Gate resistance	R_g		-	6	12	
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -6\text{ V}$, $R_L = 1\text{ }\Omega$ $I_D \equiv -10\text{ A}$, $V_{GEN} = -4.5\text{ V}$, $R_g = 1\text{ }\Omega$	-	25	50	ns
Rise time	t_r		-	25	50	
Turn-off delay time	$t_{d(off)}$		-	70	140	
Fall time	t_f		-	50	100	
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -10\text{ V}$, $R_L = 1\text{ }\Omega$ $I_D \equiv -10\text{ A}$, $V_{GEN} = -8\text{ V}$, $R_g = 1\text{ }\Omega$	-	10	20	
Rise time	t_r		-	20	40	
Turn-off delay time	$t_{d(off)}$		-	90	180	
Fall time	t_f		-	46	90	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	$T_C = 25\text{ }^\circ\text{C}$	-	-	-12	A
Pulse diode forward current	I_{SM}		-	-	-50	
Body diode voltage	V_{SD}	$I_S = -10\text{ A}$, $V_{GS} = 0\text{ V}$	-	-0.8	-1.2	V
Body diode reverse recovery time	t_{rr}	$I_F = -10\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, $T_J = 25\text{ }^\circ\text{C}$	-	60	120	ns
Body diode reverse recovery charge	Q_{rr}		-	39	80	nC
Reverse recovery fall time	t_a		-	22	-	ns
Reverse recovery rise time	t_b		-	38	-	

Notes

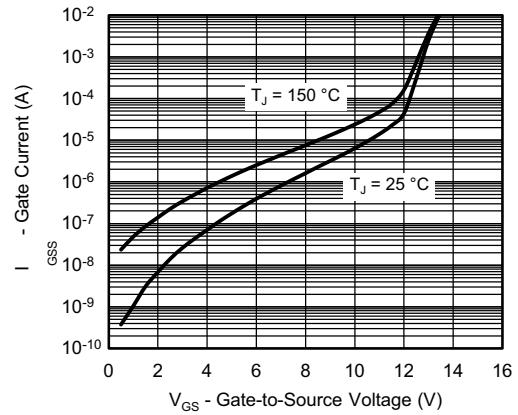
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

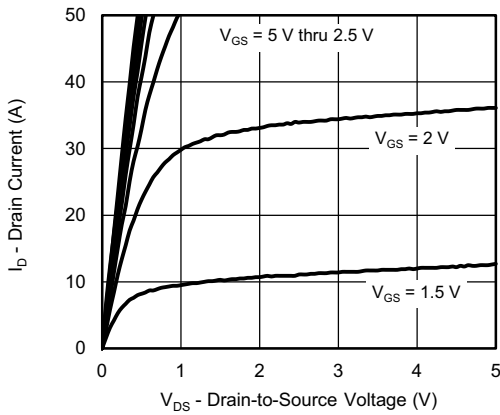
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



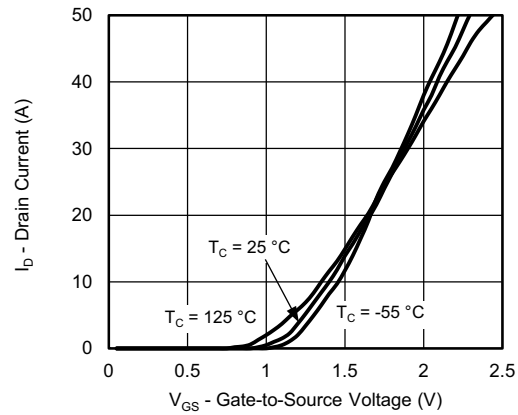
Gate Current vs. Gate-Source Voltage



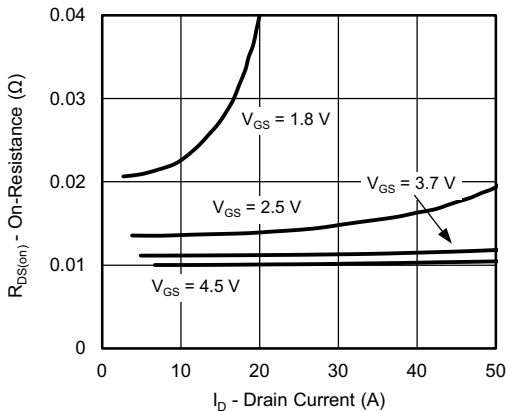
Gate Current vs. Gate-Source Voltage



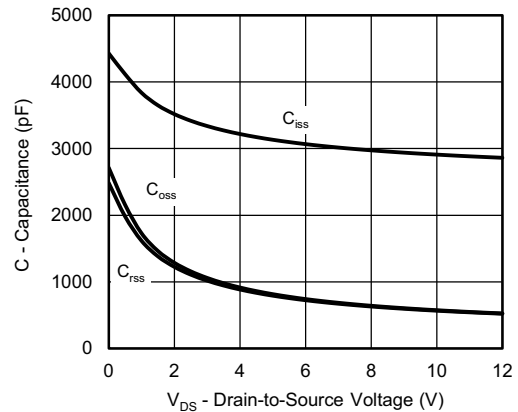
Output Characteristics



Transfer Characteristics



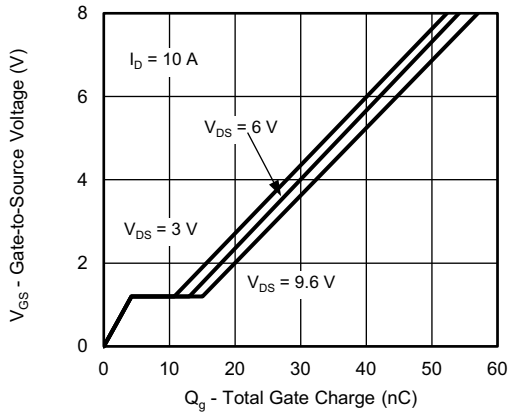
On-Resistance vs. Drain Current



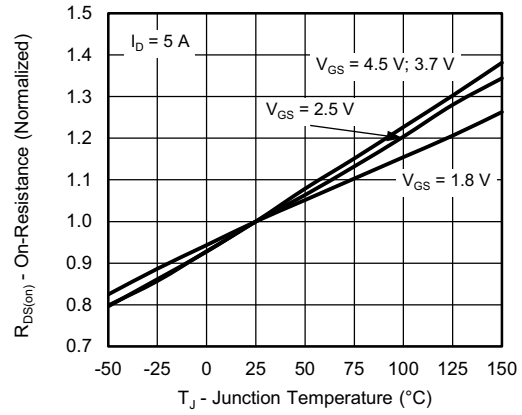
Capacitance



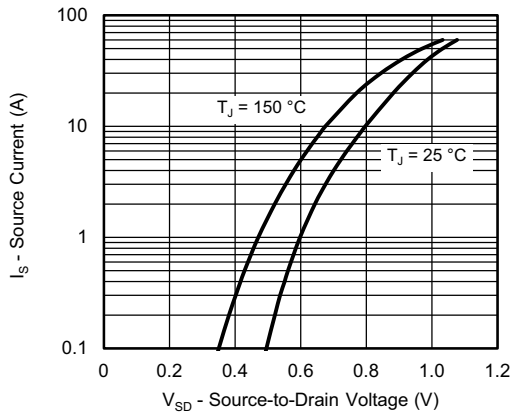
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



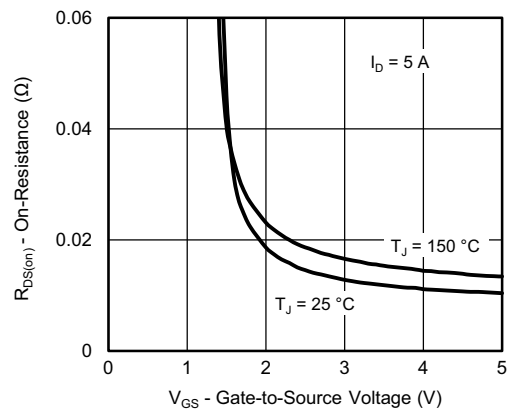
Gate Charge



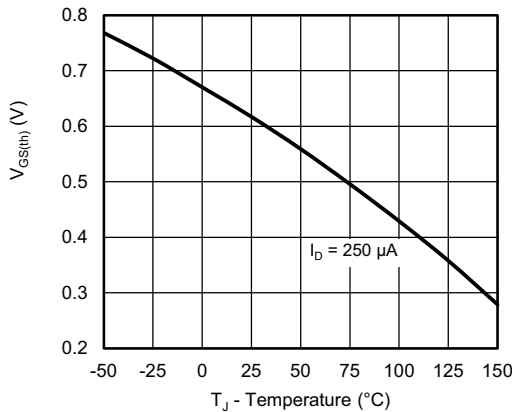
On-Resistance vs. Junction Temperature



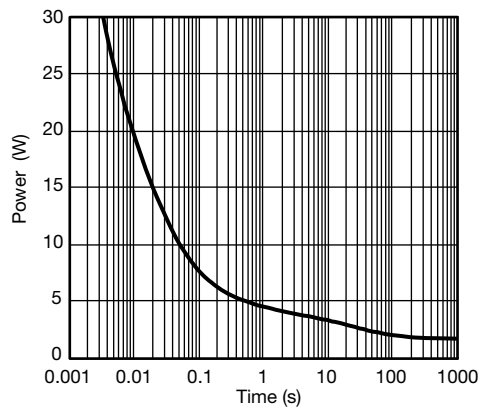
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



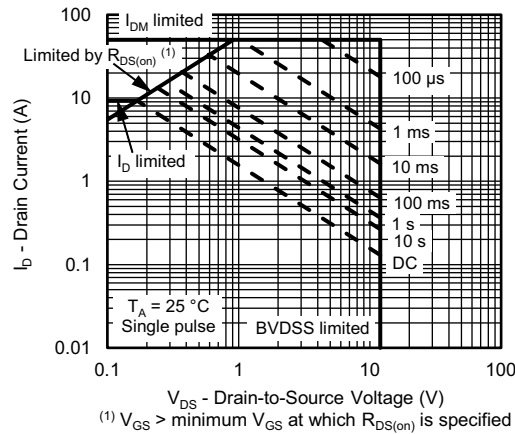
Threshold Voltage



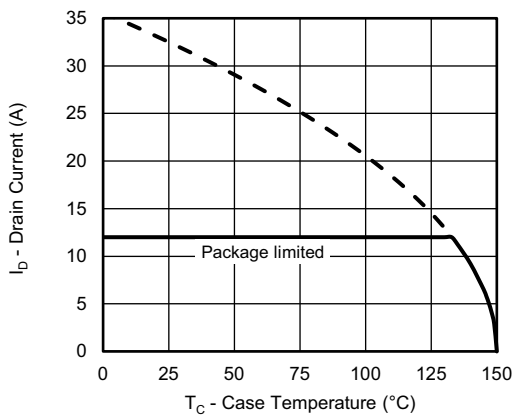
Single Pulse Power, Junction-to-Ambient



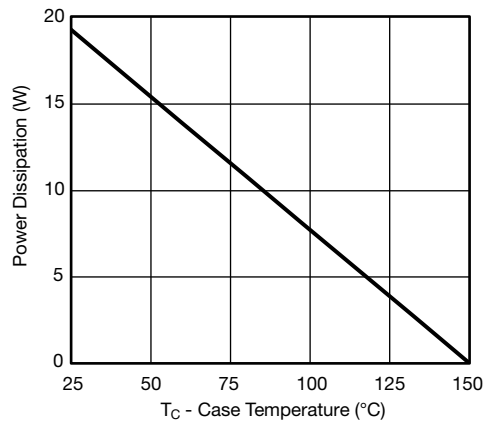
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Safe Operating Area, Junction-to-Ambient



Current Derating ^a



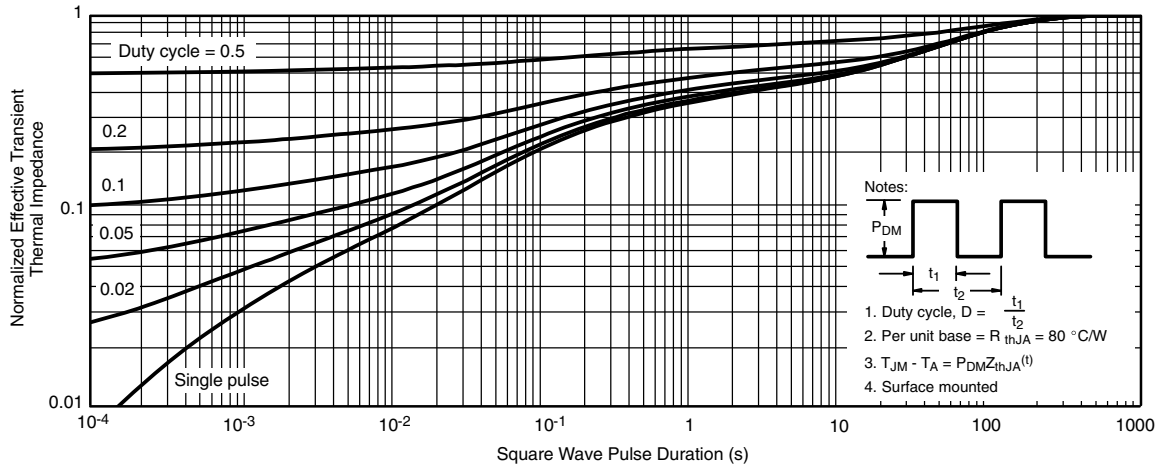
Power Derating

Note

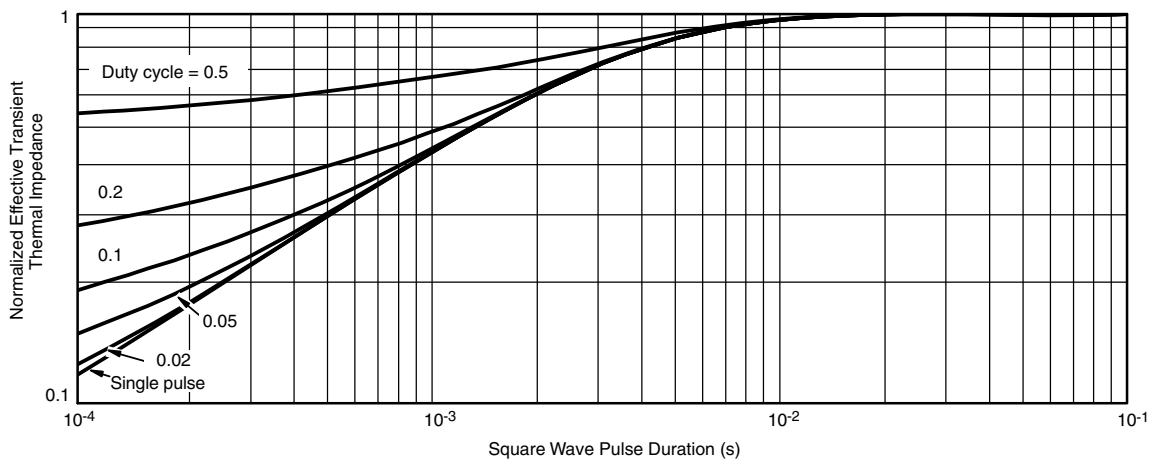
- a. The power dissipation P_D is based on $T_J \text{ max.} = 150 \text{ }^\circ\text{C}$, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

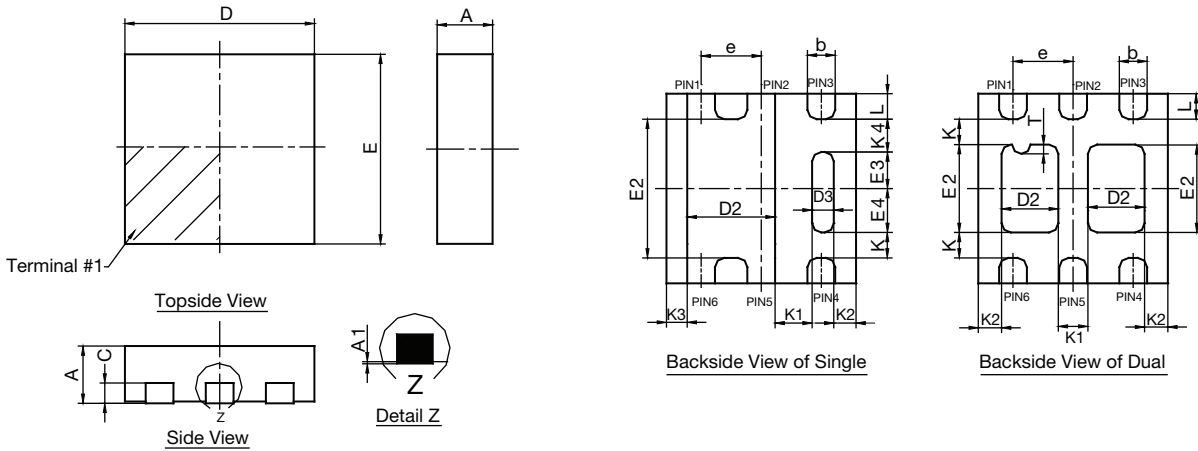


Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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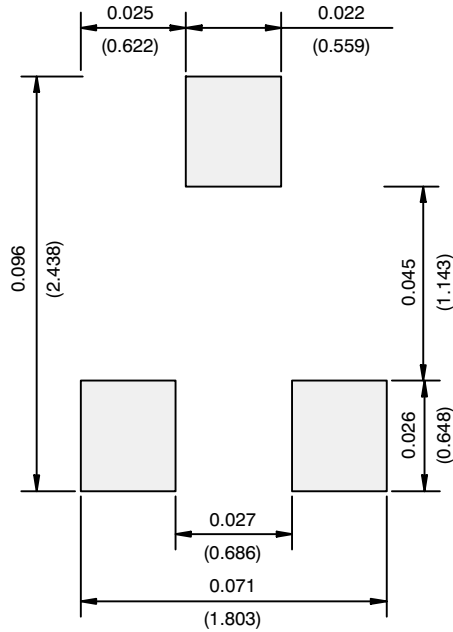
Case Outline for PowerPAK® SC70T


DIM.	SINGLE PAD						DUAL PAD					
	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.525	0.60	0.65	0.0206	0.024	0.026	0.525	0.60	0.65	0.0206	0.024	0.026
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
C	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D2	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D3	0.135	0.235	0.335	0.005	0.009	0.013						
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E2	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E3	0.345	0.395	0.445	0.014	0.016	0.018						
E4	0.425	0.475	0.525	0.017	0.019	0.021						
e	0.65 BSC			0.026 BSC			0.65 BSC			0.026 BSC		
K	0.275 TYP.			0.011 TYP.			0.275 TYP.			0.011 TYP.		
K1	0.400 TYP.			0.016 TYP.			0.320 TYP.			0.013 TYP.		
K2	0.240 TYP.			0.009 TYP.			0.252 TYP.			0.010 TYP.		
K3	0.225 TYP.			0.009 TYP.								
K4	0.355 TYP.			0.014 TYP.								
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
T							0.05	0.10	0.15	0.002	0.004	0.006
ECN: C12-0160-Rev. B, 05-Mar-12 DWG: 5994												

Notes

1. All dimensions are in millimeter. Millimeters will govern.
2. Package outline exclusive of mold flash and metal burr.
3. Package outline inclusive of plating

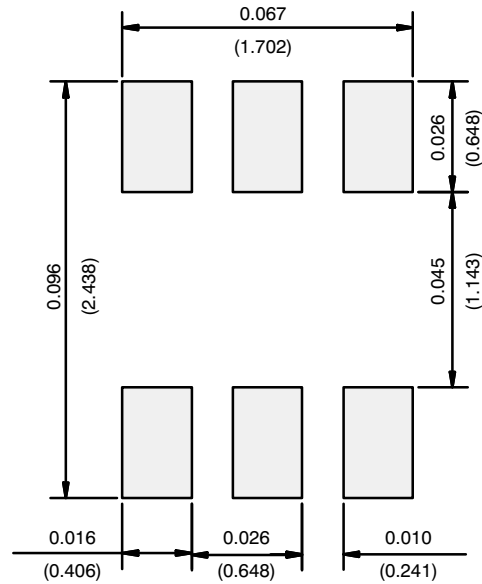
RECOMMENDED MINIMUM PADS FOR SC-70: 3-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)

RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



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